

35.C13630



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PATENT APPLICATION

6/CFR  
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
MASAAKI IWANE ET AL. ) : Examiner: N/Y/A  
Appln. No.: 09/346,678 ) : Group Art Unit: 2812  
Filed: July 2, 1999 ) :  
For: CRYSTAL GROWTH PROCESS, ) :  
SEMICONDUCTOR DEVICE, AND :  
ITS PRODUCTION PROCESS ) : March 8, 2000

Assistant Commissioner for Patents  
Washington, D.C. 20231

TO: CHIEF ROOM

REQUEST FOR CORRECTED FILING RECEIPT

Sir:

Applicants' attorneys have received an official Filing Receipt in the above-identified application in which the following inaccuracy is noted:

The name of the first inventor is incorrect and should read as follows: --MASAAKI IWANE--.

Issuance of a corrected Filing Receipt with the above noted corrections is respectfully requested.

Applicants' undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our below listed address.

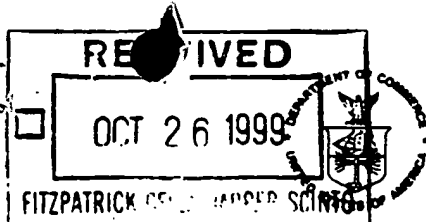
Respectfully submitted,

  
Attorney for Applicants

Registration No. 28,46

FITZPATRICK, CELLA, HARPER & SCINTO  
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New York, New York 10112-3801  
Facsimile: (212) 218-2200

FILING RECEIPT  
CORRECTED

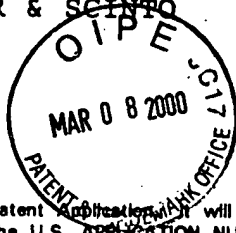


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APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
09/346,678	07/02/99	2812	\$890.00	35.C13630	9	9	3

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NEW YORK NY 10112



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Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts of Application" ("Missing Parts Notice") in this application, please submit any corrections to this Filing Receipt with your reply to the "Missing Parts Notice." When the PTO processes the reply to the "Missing Parts Notice," the PTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s) NASAAKI IWANE, ATSUGI-SHI, JAPAN; KATSUMI NAKAGAWA, ATSUGI-SHI, JAPAN; SHOJI NISHIDA, HIRATSUKA-SHI, JAPAN; NORITAKA UKIYO, ATSUGI-SHI, JAPAN; YUKIKO IWASAKI, ATSUGI-SHI, JAPAN; MASAKI MIZUTANI, ISEHARA-SHI, JAPAN.

FOREIGN APPLICATIONS-	JAPAN	10-202867	03/07/98
	JAPAN	11-188466	02/07/99

IF REQUIRED, FOREIGN FILING LICENSE GRANTED 08/03/99

TITLE

CRYSTAL GROWTH PROCESS, SEMICONDUCTOR DEVICE, AND ITS PRODUCTION PROCESS

PRELIMINARY CLASS: 438

TC: 1001

DATA ENTRY BY: BATES, DIANE

TEAM: 03 DATE: 10/19/99

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(See reverse for new important information)



Bib Data Sheet

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Patent and Trademark OfficeAddress: COMMISSIONER OF PATENTS AND TRADEMARKS  
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<b>SERIAL NUMBER</b> 09/346,678	<b>FILING DATE</b> 07/02/1999 <b>RULE</b> -	<b>CLASS</b> 257	<b>GROUP ART UNIT</b> 2815	<b>ATTORNEY DOCKET NO.</b> 35.C13630
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**APPLICANTS**  
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 MASAKI MIZUTANI, ISEHARA-SHI, JAPAN;

**\*\* CONTINUING DATA \*\*\*\*\***  
*nee*

**\*\* FOREIGN APPLICATIONS \*\*\*\*\***  
 JAPAN 10-202887 03/07/1998  
 JAPAN 11-188466 02/07/1999  
*07/03/1998*  
*07/02/1999*

**IF REQUIRED, FOREIGN FILING LICENSE GRANTED**  
 \*\* 08/03/1999 -

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWING</b> 9	<b>TOTAL CLAIMS</b> 9	<b>INDEPENDENT CLAIMS</b> 3
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after				
Verified and Acknowledged Examiner's Signature: <i>[Signature]</i> Initials: <i>[Initials]</i>				

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**TITLE**  
 CRYSTAL GROWTH PROCESS, SEMICONDUCTOR DEVICE, AND ITS PRODUCTION PROCESS

<b>FILING FEE RECEIVED</b> 890	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
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		<input type="checkbox"/> 1.18 Fees ( Issue )
		<input type="checkbox"/> Other _____
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